# 

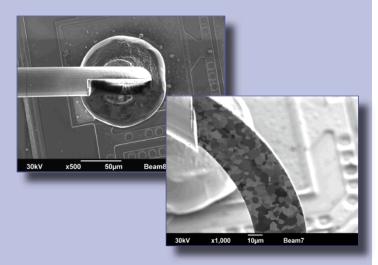
# **MultiBeam**

## High performance SEM and micro milling FIB

New, easy-to-use MultiBeam system combines high resolution ion optics with the most popular SEM column in the world. The JIB-4500 MultiBeam offers increased throughput and productivity for a variety of applications, from viewing to analysis to micro milling.

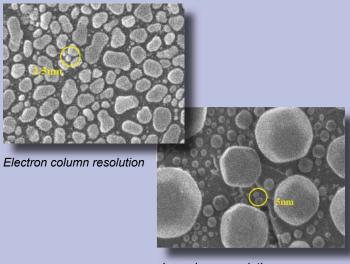
### Large current milling mode

 Enhances throughput from large milling area (maximum milling current 30 nA).



# High resolution electron (LaB<sub>6</sub>) and ion optics

 Provides stable imaging for milling/monitoring over extended periods of time.



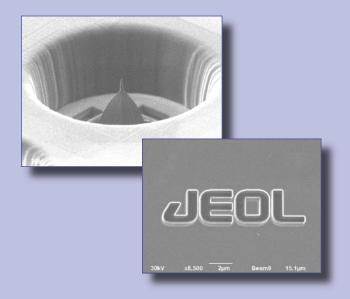
Ion column resolution

### Charge-free imaging and analysis

 Low vacuum system standard for non-conductive specimens

### Bitmap milling system

- Enables deposition and milling of binary image data stored in BMP file.
- Supports 3D nano milling with continuous access to multiple bitmap data.



# Standard airlock system for fast and easy sample loading

- Fast sample loading through airlock chamber.
- Maximum sample size: 150mm wafer.

# Low mag mode identifies milling positions

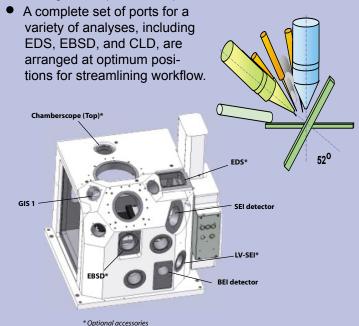
- Milling position initially identified at minimum magnification of 5X in SEM.
- Transition to milling mode is easily made at minimum magnification of 30X in FIB.

### Monitor milling in real time

- Simultaneous SEM imaging of FIB milling process.
- Effectively prepares TEM thin film samples to optimum thickness.

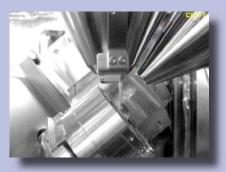
### A complete set of ports for all your applications

Large stage is capable of image milling of sample areas up to 76mm.



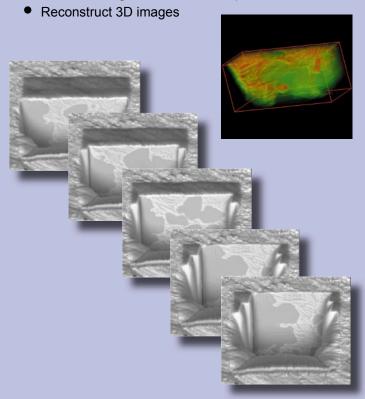
### Optional chamberscope verifies sample positions

Effective for verifying positional relationships with other options including gas injection system.



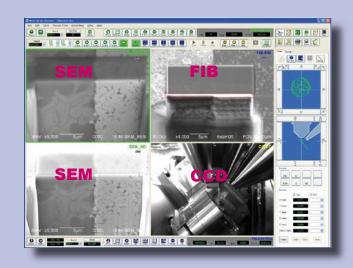
# Serial slicing and sampling - S<sup>3™</sup>

Monitor slicing and fabrication in process.



### User friendly, easy to learn

- Modern, clearly marked GUI.
- Visual, intuitive operation from SEM/FIB condition setting to milling and monitoring.



# **MultiBeam**

# High performance SEM and micro milling FIB

### **Principal Specifications**

### **FIB**

Ion source Ga liquid metal ion source

Resolution 5nm @ 30kV
Accelerating voltage 1 to 30kV (in steps)
Magnification 30x (for wide view)

Maximum beam current 100X to 300,000X 30nA (at 30kV)

**SEM** 

Beam source LaB6

Resolution 2.5nm @ 30kV
Accelerating voltage 0.3 to 30kV (in steps)
Magnification 5X to 300,000X
Maximum beam current 1,000nA (at 30kV)
Goniometer stage X: 76mm; Y: 76mm;

Z: 5 to 48mm

Z' for eucentric point adjustment

T: -100 to 900; R: 3600 endless

Vacuum pump SIP (x2), TMP/RP (x2) Standard features Low vacuum (LV)

Backscatter detector (BEI)
Gas injection unit (1)

### **Installation Requirements**

Power Single phase 100V± 10%

50/60 Hz, 3 kVA (x2)

Ground One, 100 ohm or less

Dry nitrogen gas 0.4 to 0.7 MPa Room temperature 18 to 25°C Humidity 60% or less

Specifications subject to change without notice.



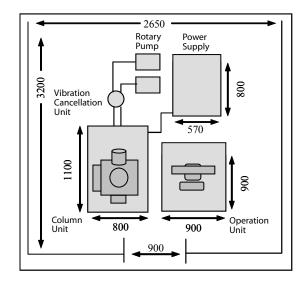
### **Optional Attachments**

Chamber scope - top mount/side mount

Gas injection system

External scan interface for SEM

EDS, EBSD, CLD





For more information, contact your local sales office, email salesinfo@jeol.com, or visit www.jeolusa.com.

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